

January 2015

J111 / J112 / J113 / MMBFJ111 / MMBFJ112 / MMBFJ113 N-Channel Switch

Features

- This device is designed for low level analog switching, sample and hold circuits and chopper stabilized amplifiers.
- Sourced from process 51
- Source & Drain are interchangeable.



Figure 1. J111 / J112 / J113 Device Package

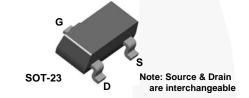


Figure 2. MMBFJ111 / MMBFJ112 / MMBFJ113 Device Package

Ordering Information

| Part Number | Top Mark | Package | Packing Method | |
|-------------|----------------------------|----------|----------------|--|
| J111 | J111 J111 | | Bulk | |
| J111_D26Z | J111_D26Z J111 | | Tape and Reel | |
| J111_D74Z | J111_D74Z J111 | | Ammo | |
| J112 | J112 J112 | | Bulk | |
| J112_D26Z | J112 | TO-92 3L | Tape and Reel | |
| J112_D27Z | J112 | TO-92 3L | Tape and Reel | |
| J112_D74Z | J112 | TO-92 3L | Ammo | |
| J113 | J113 | TO-92 3L | Bulk | |
| J113_D74Z | J113 | TO-92 3L | Ammo | |
| J113_D75Z | J113 | TO-92 3L | Ammo | |
| MMBFJ111 | MMBFJ111 6P SOT-23 3L | | Tape and Reel | |
| MMBFJ112 | MMBFJ112 6R | | Tape and Reel | |
| MMBFJ113 | 6S SOT-23 3L Tape and Reel | | | |

Absolute Maximum Ratings(1), (2)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25$ °C unless otherwise noted.

| Symbol | Parameter | Value | Unit |
|-----------------------------------|--|------------|------|
| V_{DG} | Drain-Gate Voltage | 35 | V |
| V_{GS} | Gate-Source Voltage | -35 | V |
| I _{GF} | Forward Gate Current | 50 | mA |
| T _J , T _{STG} | Operating and Storage Junction Temperature Range | -55 to 150 | °C |

Notes:

- 1. These ratings are based on a maximum junction temperature of 150°C.
- 2. These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty-cycle operations.

Thermal Characteristics

Values are at $T_A = 25$ °C unless otherwise noted.

| | | Ma | | |
|-----------------|---|--------------------------------------|---|-------|
| Symbol | Parameter | J111 / J112 / J113 ⁽³⁾ | MMBFJ111 / MMBFJ112 / MMBFJ113 ⁽⁴⁾ | Unit |
| P _D | Total Device Dissipation | 625 | 350 | mW |
| r _D | Derate Above 25°C | 5.0 | 2.8 | mW/°C |
| $R_{\theta JC}$ | Thermal Resistance, Junction-to-Case 125 | | °C/W | |
| $R_{\theta JA}$ | Thermal Resistance, Junction-to-Ambient 200 357 | | | °C/W |

Notes:

- 3. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.
- 4. Device mounted on FR-4 PCB 36mm × 18mm × 1.5mm; mounting pad for the collector lead minimum 6cm².

Electrical Characteristics

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

| Parameter | Conditions | | Min. | Max. | Unit |
|--|--|--|------|-------|------|
| cteristics | | | • | • | • |
| Gate-Source Breakdown Voltage | $I_G = -1.0 \mu\text{A}, V_{DS} = 0$ | | -35 | | V |
| Gate Reverse Current | $V_{GS} = -15 \text{ V}, V_{DS} = 0$ | | | -1.0 | nA |
| | | 111 | -3.0 | -10.0 | |
| Gate-Source Cut-Off Voltage | $V_{DS} = 15 \text{ V}, I_{D} = 1.0 \mu\text{A}$ | 112 | -1.0 | -5.0 | V |
| | | 113 | -0.5 | -3.0 | 1 |
| Drain Cutoff Leakage Current | $V_{DS} = 5.0 \text{ V}, V_{GS} = -10 \text{ V}$ | • | | 1.0 | nA |
| teristics | | | | • | • |
| | | 111 | 20 | | |
| Zero-Gate Voltage Drain Current ⁽⁵⁾ | $V_{DS} = 15 \text{ V}, V_{GS} = 0$ | 112 | 5.0 | | mA |
| | | 113 | 2.0 | | |
| | | 111 | | 30 | |
| Drain-Source On Resistance | $V_{DS} \le 0.1 \text{ V}, V_{GS} = 0$ | 112 | | 50 | Ω |
| | | 113 | | 100 | |
| nal Characteristics | | 1 | | • | |
| Drain-Gate &Source-Gate On Capacitance | $V_{DS} = 0, V_{GS} = 0, f = 1.0 M$ | lHz | | 28 | pF |
| Drain-Gate Off Capacitance $V_{DS} = 0$, $V_{GS} = -10 \text{ V}$, $f = 1.0 \text{ MHz}$ | | | 5.0 | pF | |
| Source-Gate Off Capacitance | $V_{DS} = 0$, $V_{GS} = -10$ V, $f = 1$ | .0 MHz | | 5.0 | pF |
| | Gate-Source Breakdown Voltage Gate Reverse Current Gate-Source Cut-Off Voltage Drain Cutoff Leakage Current Steristics Zero-Gate Voltage Drain Current Drain-Source On Resistance Drain-Gate &Source-Gate On Capacitance Drain-Gate Off Capacitance | citeristics Gate-Source Breakdown Voltage $I_G = -1.0 \mu A$, $V_{DS} = 0$ Gate Reverse Current $V_{GS} = -15 \text{ V}$, $V_{DS} = 0$ Gate-Source Cut-Off Voltage $V_{DS} = 15 \text{ V}$, $V_{DS} = 1.0 \mu A$ Drain Cutoff Leakage Current $V_{DS} = 5.0 \text{ V}$, $V_{GS} = -10 \text{ V}$ Cero-Gate Voltage Drain Current(5) $V_{DS} = 15 \text{ V}$, $V_{GS} = 0$ Drain-Source On Resistance $V_{DS} = 0.1 \text{ V}$, $V_{GS} = 0$ Drain-Gate &Source-Gate On Capacitance $V_{DS} = 0$, $V_{GS} = 0$, $V_{GS} = -10 \text{ V}$, $V_{GS} = 1.0 \text{ M}$ Drain-Gate Off Capacitance $V_{DS} = 0$, $V_{GS} = -10 \text{ V}$, $V_{GS} = 1.0 \text{ M}$ | | | |

Note:

5. Pulse test: pulse width \leq 300 μ s, duty cycle \leq 2%.

Typical Performance Characteristics

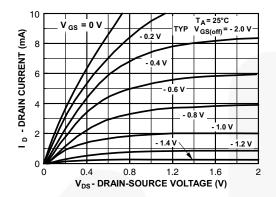


Figure 3. Common Drain-Source

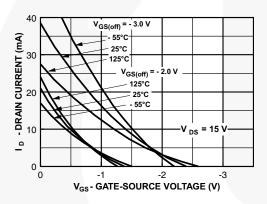


Figure 5. Transfer Characteristics

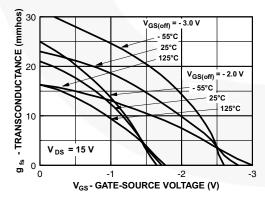


Figure 7. Transfer Characteristics

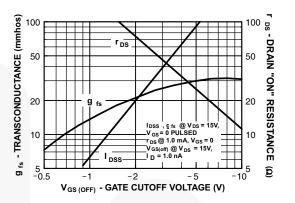


Figure 4. Parameter Interactions

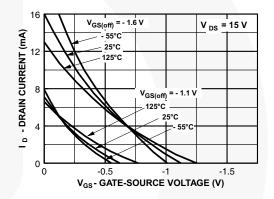


Figure 6. Transfer Characteristics

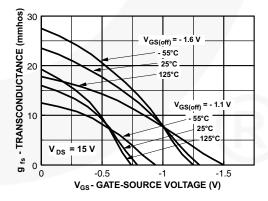


Figure 8. Transfer Characteristics

Typical Performance Characteristics (Continued)

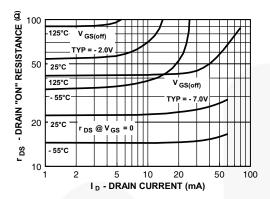


Figure 9. On Resistance vs. Drain Current

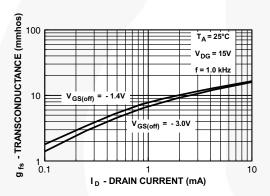


Figure 11. Transconductance vs. Drain Current

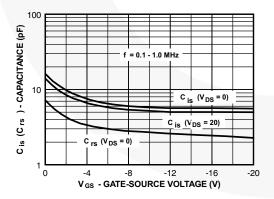


Figure 13. Capacitance vs. Voltage

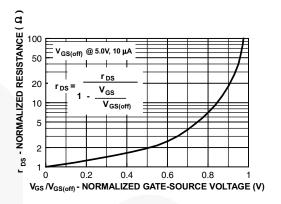


Figure 10. Normalized Drain Resistance vs.

Bias Voltage

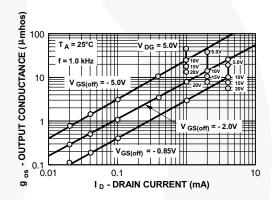


Figure 12. Output Conductance vs. Drain Current

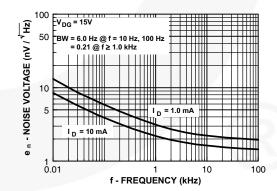


Figure 14. Noise Voltage vs. Frequency

Typical Performance Characteristics (Continued)

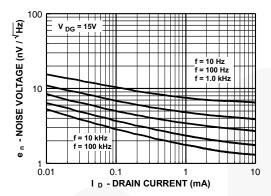


Figure 15. Noise Voltage vs. Current

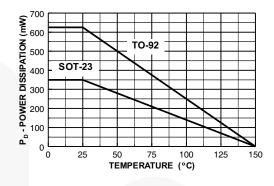


Figure 16. Power Dissipation vs. Ambient Temperature

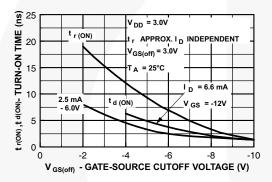


Figure 17. Switching Turn-On Time vs. Gate-Source Voltage

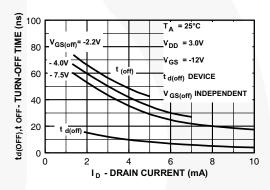
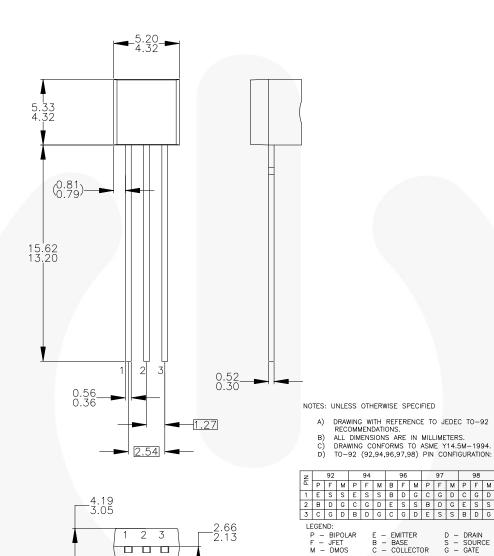


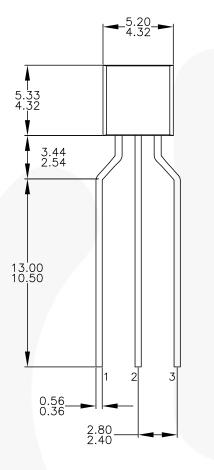
Figure 18. Switching Turn-Off Time vs. Drain Current

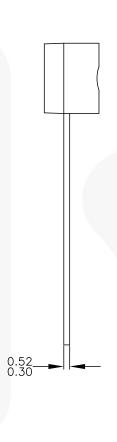
Physical Dimensions

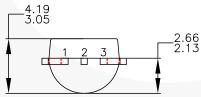


E) FOR PACKAGE 92, 94, 96, 97 AND 98:
PIN CONFIGURATION DRAIN "D" AND SOURCE "S"
ARE INTERCHANGEAGLE AT JFET "F" OPTION.
F) DRAWING FILENAME: MKT—ZAO3DREV3.

Physical Dimensions (Continued)







NOTES: UNLESS OTHERWISE SPECIFIED

- DRAWING CONFORMS TO JEDEC MS-013, VARIATION AC. ALL DIMENSIONS ARE IN MILLIMETERS. DRAWING CONFORMS TO ASME Y14.5M-2009. DRAWING FILENAME: MKT-ZAO3FREV3. FAIRCHILD SEMICONDUCTOR.

Figure 20. 3-Lead, TO-92, Molded, 0.2 In Line Spacing Lead Form, Ammo, Tape and Reel Type

Physical Dimensions (Continued) 0.95 2.92±0.20 3 1.40 1.30+0.20 2.20 2 0.60 0.37 (0.29) -0.95 ⊕ 0.20 M A B 1.00 1.90 1.90 LAND PATTERN RECOMMENDATION SEE DETAIL A -1.20 MAX 0.10 (0.93) ○ 0.10 ○ C С 2.40±0.30 NOTES: UNLESS OTHERWISE SPECIFIED **GAGE PLANE** A) REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE H. B) ALL DIMENSIONS ARE IN MILLIMETERS. 0.23 C) DIMENSIONS ARE INCLUSIVE OF BURRS, 0.25 MOLD FLASH AND TIE BAR EXTRUSIONS. D) DIMENSIONING AND TOLERANCING PER ASME Y14.5M - 1994. 0.20 MIN SEATING E) DRAWING FILE NAME: MA03DREV10 **PLANE** (0.55)**DETAIL A** SCALE: 2X

Figure 21. 3-LEAD, SOT23, JEDEC TO-236, LOW PROFILE





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